NSN 5961-01-047-1834

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-047-1834 **Inclosure Material:** Metal **Overall Length:** 0.190 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.220 inches **Function For Which Designed:** Amplifier Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 20.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 50.00 milliamperes drain current all transistor **Power Rating Per Characteristic:** 330.0 milliwatts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0